TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

# 2SA1832FT

### Audio frequency General Purpose Amplifier Applications

Unit: mm

• High voltage: VCEO = -50 V

• High current:  $I_C = -150 \text{ mA (max)}$ 

• High  $h_{FE}$ :  $h_{FE} = 120$  to 400

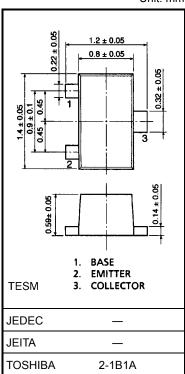
• Excellent hFE linearity

:  $h_{FE}$  ( $I_{C} = -0.1$  mA)/ $h_{FE}$  ( $I_{C} = -2$  mA) = 0.95 (typ.)

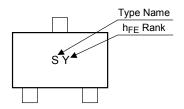
• Complementary to 2SC4738F

## **Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	Ic	-150	mA
Base current	Ι <sub>Β</sub>	-30	mW
Collector power dissipation	PC	100	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	-55 to 125	°C



# Marking



# **Electrical Characteristics (Ta = 25°C)**

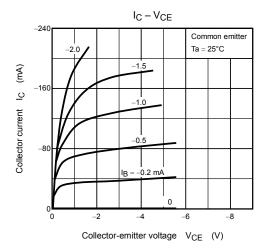
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -50 \text{ V}, I_E = 0$	_	_	-0.1	μА
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -5 V, I_C = 0$			-0.1	μΑ
DC current gain	h <sub>FE</sub> (Note)	$V_{CE} = -6 \text{ V}, I_B = -2 \text{ mA}$	120		400	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	$I_C = -100 \text{ mA}, I_B = -10 \text{ mA}$	I	-0.1	-0.3	V
Transition frequency	f <sub>T</sub>	$V_{CE} = -10 \text{ V}, I_{C} = -1 \text{ mA}$	80		_	MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		4	7	pF

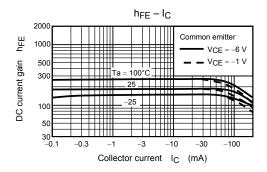
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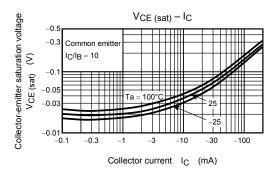
Note: hFE Classification

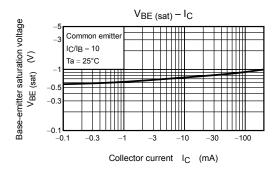
Y (Y): 120 to 140, GR (G): 200 to 400

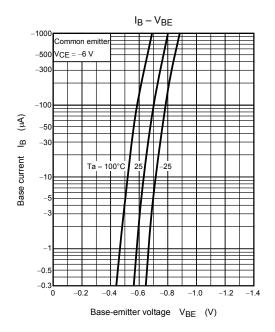
( ) Marking symbol

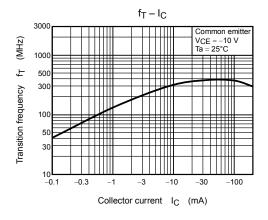


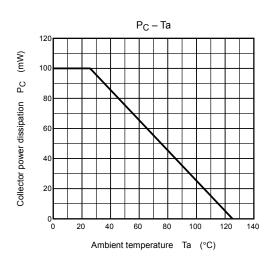












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